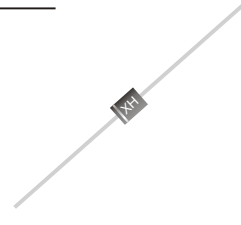
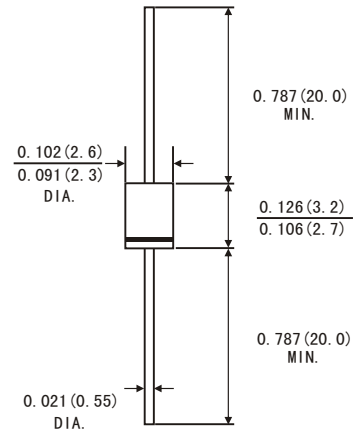


FEATURES

- The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



R-1



Dimensions in inches and (millimeters)

MECHANICAL DATA

- *Case:* R-1 molded plastic body
- *Terminals:* Lead solderable per MIL-STD-750, method 2026
- *Polarity:* Color band denotes cathode end
- *Mounting Position:* Any
- *Weight:* 0.007ounce, 0.19 gram

MAXIMUM RATINGS (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	Ambient temperature = 55°C	I_O			1.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	I_{FSM}			30	A
Reverse current	$V_R = V_{RRM}$ $T_A = 25^\circ\text{C}$	I_R			5.0	μA
	$V_R = V_{RRM}$ $T_A = 100^\circ\text{C}$				100	μA
Thermal resistance	Junction to ambient	R_{qJA}		42		$^\circ\text{C} / \text{w}$
Diode junction capacitance	f=1MHz and applied 4VDC reverse voltage	C_J		15		pF
Storage temperature		T_{STG}	-55		+150	$^\circ\text{C}$

SYMBOLS	MARKING CODE	V_{RRM}^{*1} (V)	V_{RMS}^{*2} (V)	V_R^{*3} (V)	V_F^{*4} (V)	T_{RR}^{*5} (nS)	Operating temperature ($^\circ\text{C}$)
FFM101-M	1F1	50	35	50	1.3	150	-55 to +150
FFM102-M	1F2	100	70	100			
FFM103-M	1F3	200	140	200			
FFM104-M	1F4	400	280	400			
FFM105-M	1F5	600	420	600			
FFM106-M	1F6	800	560	800			
FFM107-M	1F7	1000	700	1000			

*1 Repetitive peak reverse voltage

*2 RMS voltage

*3 Continuous reverse voltage

*4 Maximum forward voltage

*5 Reverse recovery time

FIG.1-TYPICAL FORWARD CHARACTERISTICS

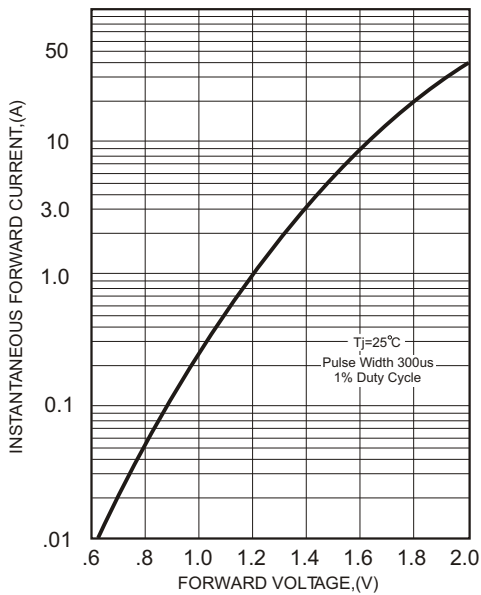


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

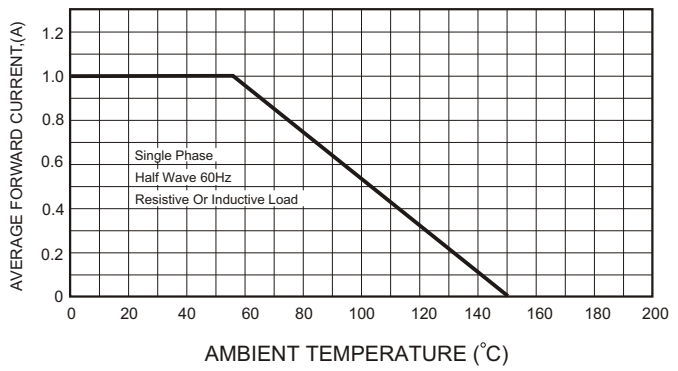
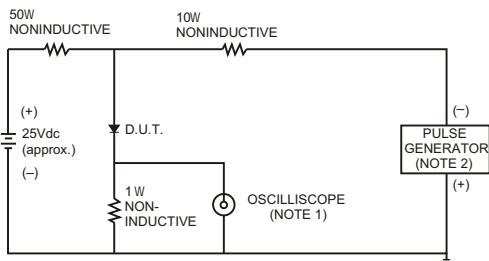


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

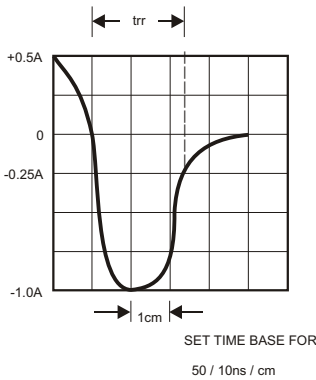


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

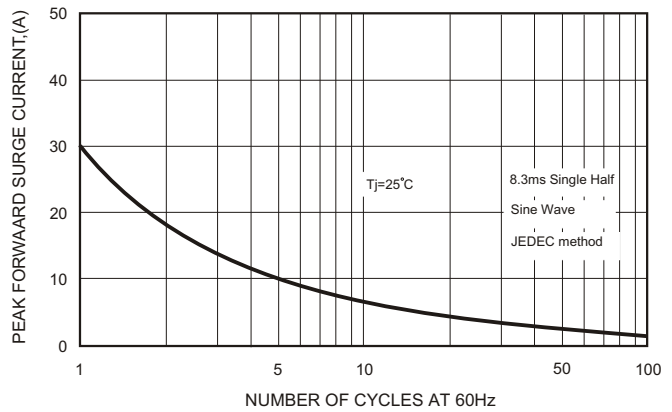


FIG.5-TYPICAL JUNCTION CAPACITANCE

